Particle-in-cell/Monte Carlo simulation of a capacitively coupled radio frequency Ar/CF$_4$ discharge: Effect of gas composition

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A one-dimensional particle-in-cell/Monte Carlo model is developed to study a capacitively coupled radio frequency discharge in a gas mixture of argon and CF$_4$. The simulation takes into account the following charged particles: electrons, two kinds of positive ions (Ar$^+$, CF$_4^+$), and two kinds of negative ions (F$^-$, CF$_3^-$). The model considers electron–Ar collisions, electron–CF$_4$ collisions, various kinds of collisions of CF$_3^+$, F$^-$, CF$_3^-$, or Ar$^+$ with Ar or CF$_4$, and positive–negative ion recombination. The probability for the positive–negative ion recombination is determined from a recombination rate constant. The ion–neutral elastic and reactive collisions are simulated by an ion–molecule collision model for endothermic reactions. The typical results of this model are electron and ion densities, fluxes and energy distributions, collision rates, and electric field and potential distributions. The simulation is performed for 0.1/0.9, 0.5/0.5, and 0.9/0.1 ratios of a Ar/CF$_4$ mixture, as well as for pure Ar and pure CF$_4$ discharges at a pressure of 200 mTorr. It is observed that at high CF$_4$ concentration the discharge behaves as a typical electronegative discharge and that CF$_3^+$ is the major positive ion. At low CF$_4$ concentration, keeping the other operating parameters the same, the double layer structure and the electron density maxima at the bulk–sheath interface, which are representative for an electronegative discharge, disappear and the Ar$^+$ density exceeds the CF$_3^+$ density by more than 1 order of magnitude. The results show that the F$^-$ ions are the dominant negatively charged species for all Ar/CF$_4$ ratios investigated. © 2003 American Institute of Physics. [DOI: 10.1063/1.1542920]

I. INTRODUCTION

Glow discharges find an increasing application in the microelectronics industry to modify the surface properties of materials in particular for the deposition of thin films and for plasma etching of metals and semiconductors. Radio frequency (rf) plasma etching is well recognized for its anisotropy, which is a critical process parameter in integrated circuit manufacture, and the study of this plasma processing is therefore of great interest. A variety of reactors and feedgas mixtures are used in this application. Carbon tetrafluoride CF$_4$ and its mixes are widely used in plasma etching of silicon and silicon dioxide. In order to achieve high-resolution plasma processing it is important to understand the discharge physics and chemistry. In recent years a number of articles appeared dealing with high-density inductively coupled CF$_4$ and Ar/CF$_4$ discharges; especially diagnostic measurements and modeling. Maeshige et al. describe the design of a pulsed two-frequency capacitively coupled (cc) plasma in CF$_4$/Ar for sustaining a high-density plasma and discuss its ability to generate charge-free processes for producing high-aspect-ratio holes or trench etching. However, simulations and experimental data for conventional cc rf discharges in Ar/CF$_4$ mixtures in the open literature are very scarce. Rauf and Kushnir investigated numerically the argon metastable densities in Ar/CF$_4$ discharges. Kaga et al. present measurements of the charged particle densities and electron energy distribution function (EEDF) and their dependences on the CF$_4$ content. The purpose of the present paper is a description of a model and systematic study of the plasma parameters in a conventional cc rf Ar/CF$_4$ discharge. The article deals with the influence of the gas composition on the discharge properties at more or less standard operating conditions. Comparison of the calculated ratio of negative ion to electron densities with the experimental data is also given.

CF$_4$ is an electronegative gas and its radicals play an important role in the etching process. The electron and ion densities and the electron temperature determine the production of the neutral radicals. Both experimental measurements and computational results of charged particle densities in pure cc rf CF$_4$ plasmas have been reported in the literature. There is a good qualitative agreement among them considering the different operating conditions. It was shown that the negative ion density in the bulk plasma exceeds the electron density by 1 order of magnitude. The abundance of negative ions is one of the main features of discharges in electronegative gases and this profoundly influences the sheath dynamics (i.e., one observes electric field reversal, double layer structure and local maxima of electron density in the sheath region).

Ar is a typical electropositive atomic gas and it is often used as an example for describing the fundamental principles of particle and energy balances in discharges. Due to its relative simplicity the rf argon discharge has been studied extensively both experimentally and by computer modeling...

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principles. The collisions between the charged particles are kinetic in nature. It is attractive because the fields and the energy model. A PIC simulation treats the charged particles in a one-dimensional particle-in-cell/Monte Carlo approach. The temperature of 0.043 eV ties are calculated from the Maxwellian distribution at an approximate frequency. Birdsall and co-workers point out many physical and chemical processes, including ion–ion recombination, have a relatively low reaction frequency.

Some of these methods, such as longer ion time steps, differ in their particle density. The present article examines the rf discharge structure in mixtures of Ar and CF$_4$ at different ratios, by means of a one-dimensional particle-in-cell/Monte Carlo (PIC/MC) model. A PIC simulation treats the charged particles in a kinetic way. It is attractive because the fields and the energy distributions are obtained self consistently from first principles. The collisions between the charged particles are added by combining the PIC model with a MC procedure. The major disadvantage of this method is that it requires a long computational time to reach convergence when the particle density is high (i.e., more “superparticles” have to be followed on a finer grid) or when an electronegative discharge is simulated. In the latter case the negative charges are confined in the bulk plasma and the only loss mechanism, i.e., ion–ion recombination, has a relatively low reaction frequency.

Assuming that the rf discharge is assumed to be in a pure cc rf CF$_4$ discharge show that the dominant positive ions are CF$_3^+$, with a density exceeding those of CF$_2^+$, CF$_+^+$, and F$^+$ by more than 2–3 orders of magnitude, and $N_{CF_3^+}=N_{F-}+N_{CF_2^-}+N_e$, where $N$ denotes the number densities in the bulk plasma. For that reason CF$_3^+$ is the only type of positive ions of CF$_4$ followed in the model. It should be mentioned, however, that in a CF$_4$ inductively coupled plasma (ICP) both measured and calculated data show that the number densities of CF$_3^+$, CF$_2^+$, CF$_+^+$, and F$^+$ are comparable at low pressure and high power in the ICP.

The interactions between the particles are treated by a Monte Carlo method, which is basically a probabilistic approach. To calculate collision probabilities, it is necessary to have the corresponding collision cross-section data, which are not always available. Hence, the present model uses several techniques to define the collision probabilities even when the collision cross sections are unknown (see below).

The electron–neutral collision probability $P_{\text{null}}$ is determined by the null collision method for each time step $\Delta t$:

$$P_{\text{null}} = 1 - \exp\left[-\nu_c \Delta t\right]$$

where $\nu_c$ is a constant collision frequency, which is obtained once at the beginning of the calculation from:

$$\nu_c = \max_j\left(n_e \max \left[\frac{2e}{m_p} \frac{1}{2} \sum \sigma_j(e)\right]\right)$$

where $n_e$ is the local density of the neutrals, which is assumed to be constant (i.e., the neutral gas is assumed uniformly distributed in the discharge), $m_p$ is the electron mass, $e$ is the kinetic energy of each of the electrons, and $\sigma_j(e)$ is the cross section of collision type $j$ between the electrons and neutrals. The colliding electrons are chosen randomly and each electron is checked for the type of collision. Vahedi and Surendra describe in detail the null collision technique as well as the method of determining the particle velocities after collision. In the present model, however, the expression for determining the electron scattering angle differs from the one proposed in Ref. 18, as it is explained in Ref. 26.

The electron–neutral collisions considered in this simulation, along with the corresponding threshold energy, and references for the cross-section data are presented in Table I. Those electron–CF$_4$ collisions which have small collision cross sections and high threshold energies, such as some ionization reactions, are not included in the simulation and are therefore not mentioned in the table either.

The Ar$^+$–Ar collision probability is determined by means of the null collision technique. In Eq. (2) $m_p$, $e$, and $\sigma_j(e)$, $j=1,2$ now denote the ion mass, the kinetic energy of the argon ion, and the cross sections for elastic isotropic scattering ($j=1$) and for scattering in the backward direction ($j=2$) (to simulate charge transfer), respectively. For more details and for the cross-section data, see Ref. 18.

The CF$_3^+$–CF$_4$, F$^+$–CF$_4$, and CF$_3^+$–CF$_4$ elastic and reactive collisions are simulated using the ion–molecule collision model for endothermic reactions developed by Nanbu and Denpoh (see Refs. 16,30, and 31). The total cross section...
\[ \sigma_i = \left( \frac{\pi \rho e^2}{\epsilon_0 \mu} \right)^{1/2} \beta_\nu^2 g^{-1}, \]  

(3)

where \( \mu \) is the reduced mass, \( e \) is the electron charge, \( \epsilon_0 \) is the dielectric constant of vacuum, \( \rho \) is the polarizability, \( g = |V_e - V_n| \) is the relative velocity, \( V_e \) and \( V_n \) being the precollision velocities of the ion and neutral particle respectively, and \( \beta_\nu \) is the value of the dimensionless impact parameter \( \beta \), for which the deflection angle is negligibly small. The value of \( \beta_\nu \) is set to 3 for both Ar and C\(_2\)F\(_4\).\(^{30,31}\) For Ar and C\(_2\)F\(_4\) the polarizability \( \rho \) is equal to 11.08\( a_0^3 \) and 19.09\( a_0^3 \), respectively, where \( a_0 \) is the Bohr radius.\(^1\)

Hence the ion–molecule collision probability, \( P_c = n_g^\Delta \sigma \Delta t \) for the time step \( \Delta t \) at a neutral gas density \( n_g \) equals

\[ P_c = \left( \frac{\pi \rho e^2}{\epsilon_0 \mu} \right)^{1/2} \beta_\nu^2 n_g \Delta t. \]  

(4)

For every colliding ion, the value of the dimensionless impact parameter \( \beta \) is determined by a random number \( R \), i.e. \( \beta = \beta_\nu (R)^{1/2} \).\(^{30}\) The critical value of \( \beta \) for reactive collisions is equal to one, i.e. for \( \beta = 1 \) a reactive collision occurs.\(^6\) It should be mentioned that a reactive collision is specified as an elastic collision with isotropic scattering whenever the colliding pair of an ion and a molecule are unchanged after the collision. For simplicity, this is called as “elastic reactive” collision further in the text. For \( \beta > 1 \), on the other hand, the collision is assumed to be elastic with anisotropic scattering. A description of how to determine the ion velocity after elastic collision with anisotropic scattering is given in Ref. 31.

In a reactive collision, the colliding ion and molecule, called reactants, form a complex, which separates to products via the \( i \)th reaction path. As mentioned above, when the products are the same as the colliding particles, the collision is specified as “elastic reactive.” The reaction rate of the \( i \)th reaction and the rate of the “elastic reactive” collision are determined by applying the Rice–Ramsperger–Kassel theory.\(^{16}\) Hence the probability \( P_{r-i} \) of generating products from the complex via the \( i \)th reaction path is given by

\[ P_{r-i} = \frac{(e - \Delta E_i)^{s-1}}{e^{s-1} + \sum (e - \Delta E_i)^{s-1}}, \]  

(5)

where \( e = \mu g^{2/3} \) is the relative kinetic energy of the reactants, \( \Delta E_i \) is the thermodynamic threshold energy of the \( i \)th reaction, \( s \) is the number of vibrational modes of the complex, and \( I \) is the number of reaction paths satisfying \( e > \Delta E_i \). The number of vibrational modes is described as \( s = (3N - 6)/2 \), where \( N \) is the number of atoms forming the complex.\(^{16}\)

Similarly, the probability of “elastic reactive” collision \( P_{el} \) is expressed by

\[ P_{el} = \frac{e^{s-1}}{e^{s-1} + \sum (e - \Delta E_i)^{s-1}}. \]  

(6)

According to the probabilities \( P_{r-i} \) and \( P_{el} \) a reaction path is randomly sampled from 1 to \( (I + 1) \), where \((I + 1)\) denotes the “elastic reactive” collision.\(^{16}\)

All reactions of C\(_2\)F\(_4\), F\(^-\), or C\(_2\)F\(_4\) with C\(_2\)F\(_4\) considered in the model and the corresponding thermodynamic threshold energies \( \Delta E \) are given in Tables II, III, and IV, respectively. All data for the reactions, the method of sampling the reaction path according to the probabilities \( P_{r-i} \) and \( P_{el} \), and the method of calculating the product velocities are adopted from Refs. 16 and 30.
TABLE III. $F^-$–$CF_4$ reactions considered in the model and the corresponding thermodynamic threshold energies $\Delta E$, adopted from Refs. 16 and 30.

<table>
<thead>
<tr>
<th>Reaction</th>
<th>$\Delta E$ (eV)</th>
</tr>
</thead>
<tbody>
<tr>
<td>$F^+ + F \rightarrow F$</td>
<td>10.1</td>
</tr>
<tr>
<td>$F^- + CF_4 + e \rightarrow F + CF_3$</td>
<td>11.0</td>
</tr>
<tr>
<td>$F^- + CF_3 + e \rightarrow F + CF_2$</td>
<td>12.0</td>
</tr>
</tbody>
</table>

In the simulation the $Ar^+ - CF_4$, $CF_3^+ - Ar$, $F^- - Ar$, and $CF_3^- - Ar$ elastic collisions are treated by means of the same technique. Anisotropic scattering is assumed for $\beta > 1$ and isotropic scattering for $\beta = 1$.

Cross-section data for positive–negative ion recombinations are hard to find in the literature. In the model the combination cross section and hence the probability is determined from a given expression for the corresponding rate constant, as proposed by Nanbu and Denpoh.22 If the number of the corresponding thermodynamic threshold energies $\Delta E$, adopted from Refs. 16 and 30.

<table>
<thead>
<tr>
<th>Reaction</th>
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<tbody>
<tr>
<td>$CF_3 + CF_4 \rightarrow \Delta E$ (eV)</td>
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</tr>
<tr>
<td>1. $CF_3 + CF_4 + e$</td>
<td>1.871</td>
</tr>
<tr>
<td>2. $F^- + CF_3 + e$</td>
<td>1.927</td>
</tr>
<tr>
<td>3. $CF_3 + CF_4 + F$</td>
<td>5.448</td>
</tr>
<tr>
<td>4. $CF_3 + CF_4 + F$</td>
<td>5.621</td>
</tr>
<tr>
<td>5. $CF_3 + F + e$</td>
<td>7.492</td>
</tr>
<tr>
<td>6. $F^- + CF_3 + F$</td>
<td>7.510</td>
</tr>
<tr>
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</tr>
<tr>
<td>8. $F^- + CF_3 + F$</td>
<td>7.598</td>
</tr>
<tr>
<td>10. $F^- + CF_3 + F$</td>
<td>9.431</td>
</tr>
</tbody>
</table>

TABLE IV. $CF_3^- - CF_4$ reactions considered in the model and the corresponding thermodynamic threshold energies $\Delta E$, adopted from Refs. 16 and 30.

<table>
<thead>
<tr>
<th>Reaction</th>
<th>$\Delta E$ (eV)</th>
</tr>
</thead>
<tbody>
<tr>
<td>$CF_3 + CF_4 \rightarrow \Delta E$ (eV)</td>
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<td>9.431</td>
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</tbody>
</table>

Terms of the calculated positive ($A^+$) and negative ions ($B^-$) in a cell with volume $V_c$ are $N_A$ and $N_B$, respectively, and if the weight of the superparticles (representing the real particles) is $W$, then the number of recombination pairs $N_r$ in a time $\Delta t_r$ in a cell is

$$N_r = W \frac{N_A N_B}{V_c} k_0 \Delta t_r,$$

where $k_0$ is the rate constant at temperature $T_0$ [i.e., the reaction rate constant is a function of temperature $T$: $k_0(T) = k_0(T_0)/T^n$, $n > 0$]. Note that $N_r$ is the number of superparticles that recombines. When the weight $W$ is different for the different kinds of ions, as in the present simulation, a revision of Eq. (7) is required and $N_A W_A$ has to be equal to $N_B W_B$, where $N_A$ and $N_B$ are the recombination numbers of superparticles of types A and B, respectively. The positive–negative ion recombinations and the corresponding rate constants are presented in Table V. The data are taken from Rauf and Kushner.10 In the simulation the recombination time step $\Delta t_r$ is taken to be $10^5$ times longer than the electron time step; the probability for recombination is, indeed, low because of the much lower ion densities in comparison with the neutral gas density.

TABLE V. Positive-negative ion recombination reactions considered in the model and the corresponding recombination rate coefficients, adopted from Ref. 10.

<table>
<thead>
<tr>
<th>Reaction</th>
<th>Rate coefficient (m$^3$ s$^{-1}$)</th>
</tr>
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<tbody>
<tr>
<td>$F^- + Ar^+ \rightarrow F + Ar$</td>
<td>$1.0 \times 10^{-13}$</td>
</tr>
<tr>
<td>$F^- + CF_4^+ \rightarrow F + CF_3$</td>
<td>$1.0 \times 10^{-13}$</td>
</tr>
<tr>
<td>$CF_3^- + Ar^+ \rightarrow CF_3 + Ar$</td>
<td>$1.0 \times 10^{-13}$</td>
</tr>
<tr>
<td>$CF_3^- + CF_4^+ \rightarrow CF_3 + CF_4$</td>
<td>$1.0 \times 10^{-13}$</td>
</tr>
</tbody>
</table>

III. RESULTS AND DISCUSSION

The calculations are performed in one dimension for Ar/CF$_4$ mixtures at molar ratios of 0.1/0.9, 0.5/0.5 and 0.9/0.1, and for pure Ar and pure CF$_4$ discharges. In Figs. 1–7 the axis at $z = 0$ is the rf powered electrode and the one at $z = 2.5$ cm is the grounded electrode. The gas temperature is set to 300 K. The simulation grid is uniform and it consists of 100 cells. The electron time step is $3.7 \times 10^{-11}$ s for an Ar discharge simulation and $7.4 \times 10^{-11}$ s for all other simulations. To speed up the calculation, the ion time step is set to be 25 times longer than the electron time step. The choice of the grid spacing and the time steps is defined by the accuracy criteria for PIC/MC codes with explicit mover.23 Typical results of this model are electron and ion densities, fluxes and energy distributions, collision rates, and electric field and potential distributions.

A. Pure Ar discharge

Figure 1 presents the simulation results of the electric field distribution at four phases (a), the charged particle density distributions (b), the average electron and argon-ion energies (c), and the time-averaged ionization rate (d) in a pure Ar discharge. In the bulk plasma the potential is nearly constant and therefore the electric field is weak. Strong electric
FIG. 1. Electric field distribution at four phases (a), electron and Ar$^+$ ion density distributions (b), average electron and Ar$^+$ ion energies (c), and time-averaged ionization rate (d) in a pure Ar discharge at $p=200$ mTorr and $\gamma=0$.

FIG. 2. Electric field distribution at four phases (a), charged particle density distributions (b), average electron and ion energies (c) and the time-averaged reaction rates (d) in a pure CF$_4$ discharge at $p=200$ mTorr and $\gamma=0$. 
fields are found in the sheath regions, where the voltage drops are concentrated. The only charged particles are $\text{Ar}^+$ ions and electrons [Fig. 1(b)]. As expected, the ion density profile is constant throughout the rf cycle, since the ions cannot follow the rapidly fluctuating electric field, whereas the electron density profile varies largely in the sheaths. At $\omega t = \pi/2$ the electron density in the left sheath is approximately equal to the $\text{Ar}^+$ density and has a more or less constant value. However, the electron density in the right sheath decreases rapidly to zero toward the grounded electrode at this time in the rf cycle. As the cycle advances, the electrons move to the right sheath and the density profile at $\omega t = 3\pi/2$ is a mirror image of that at phase $\pi/2$. At phases $0$ and $\pi$ the electron density decreases to zero toward both electrodes but less rapidly than at phases $3\pi/2$ and $\pi/2$, respectively. The electron density profile at $\omega t = \pi$ is not shown in the picture because it is very similar to the profile at $\omega t = 0$. The movement of the electrons causes the modulation of the sheath width.

The average electron energy is around 3 eV in the bulk plasma [see Fig. 1(c)] and it reaches its maximum of 4 eV in the sheath. To investigate the role of the secondary electron emission on the discharge properties the simulation was carried out with a secondary electron emission coefficient of 0.03. The results are not presented in the article since they confirm that the discharge is indeed in the $\alpha$ regime. In this regime the effect of secondary electron emission on most plasma parameters is rather small except for the average electron energy in the sheath where high electron energy peaks are observed, in agreement with previous investigations of an Ar discharge (cf. Ref. 17). The $\text{Ar}^+$ ion energy is around 0.04 eV in the bulk plasma. The argon ions are accelerated toward the electrodes in the sheath and therefore the ions have their maximum energy close to the electrodes, which is about 4.5 eV in this simulation.

The time-averaged ionization rate has maxima at the bulk–sheath interface [Fig. 1(d)]. The simulation results for the ionization rate at different phases of the rf cycle, which are not presented here, show that the right peak appears at phase 0 and the left one at phase $\pi$, i.e., the maxima of the ionization collisions do not coincide with the nonzero values of the electron density in the sheaths (see above). The ionization peaks appear because of the energy gained by the

FIG. 3. Electric field distribution at phases 0 and $\pi$ in the bulk plasma in a pure CF$_4$ discharge at $p = 200$ mTorr and $\gamma = 0$.

FIG. 4. Electric field (a) and electron density (b) at four times in the rf cycle, ion densities (c), and average electron, $\text{Ar}^+$ and $\text{F}^-$ ion energies (d) in an Ar/CF$_4$ (0.9/0.1) discharge at $p = 200$ mTorr and $\gamma = 0$. 
FIG. 5. Electric field (a) and electron density (b) at four times in the rf cycle, ion densities (c), and average electron, Ar$^+$ and F$^-$ ion energies (d) in an Ar/CF$_4$ (0.5/0.5) discharge at $p = 200$ mTorr and $\gamma = 0$.

FIG. 6. Electric field (a) and electron density (b) at four times in the rf cycle, ion densities (c), and average electron, Ar$^+$ and F$^-$ ion energies (d) in an Ar/CF$_4$ (0.1/0.9) discharge at $p = 200$ mTorr and $\gamma = 0$. 
electrons during their acceleration away from the electrodes into the discharge [cf. the maximum values of the electron energy at phase 0 and π in Fig. 1(c)].

All the characteristic features of the Ar discharge discussed here are in agreement with those available in the literature (e.g., see Refs. 1 and 17–20).

B. Pure CF4 discharge

The electric field distribution at four phases (a), the charged particle density distributions (b), the average electron and ion energies (c), and the time-averaged reaction rates (d) in a pure CF4 discharge are shown in Fig. 2. The structure of the discharge is typically electronegative and is characterized by the presence of negative ions (F− and CF4−), which are the dominant negative charged species. Indeed, the electron density in the bulk is about 50 times less than the density of the major negative ion F− [see Fig. 2(b)]. Unlike in the Ar discharge the electric field in the bulk plasma is substantial (on the order of 1000 V/m) [Figs. 2(a) and Fig. 3] since the potential is not constant. Another difference with the electropositive discharge is the appearance of the double layer structure (i.e., the local maxima or minima of the electric field) near the bulk–sheath interface, which is related to the density distribution. Moreover, a field reversal is observed at the right bulk–sheath interface at phase 0 and at the left bulk–sheath interface at phase π, respectively (see Fig. 3). The ion density profiles [Fig. 2(b)] are constant in time throughout the rf cycle, like in the Ar discharge. Since the diffusive flux of the negative ions is very low and the electric field is always directed outward, the negative ions are confined in the bulk plasma and are almost absent in the sheath. In the sheath mainly positive ions and electrons are found. The electrons move toward one of the electrodes depending on the phase of the applied potential. Their movement affects the local fields, which are developed by the differences of positive and negative ion concentration near the electrodes, and they cause the electrons to pile up in the bulk–sheath region. Hence, peaks in the electron density appear at the bulk–sheath interface, which cannot be observed in electropositive discharges.

Because of the nonzero bulk electric field the average electron energy in the bulk plasma is higher than in a pure Ar discharge and its value is around 6 eV [Fig. 2(c)]. Like in the Ar discharge high electron energy peaks are not observed in the sheath since the secondary electron emission coefficient is set to 0 (contrary to Ref. 16, where gamma has a nonzero value). All ions have constant average energy around 0.04 eV in the bulk plasma, i.e., the ion temperature is close to the gas temperature, because of the frequent collisions with the neutral molecules.1 The positive CF3+ ions gain energy in the sheath like the argon ions and their energy at the electrodes has a maximum value of around 65 eV [Fig. 2(c)]. As described above, few negative ions exist in the sheath. Negative ions are produced by electron attachment; the attachment rate is shown in Fig. 2(d). They are accelerated toward the bulk plasma and then are pushed back by the double layer. Therefore the negative ions gain energy in the sheath by oscillating between the electrodes and the bulk–sheath interface, and their average energy reaches a maximum of 8 eV [see Fig. 2(c)]. The average energy of the CF3− ions is not given because its profile and value are similar to that of the F− ions.

Time-averaged rates for ionization, electron attachment, electron detachment, positive–negative ion recombination, and CF3−–CF4 reactive collisions are shown in Fig. 2(d). The electron attachment, electron detachment, and ion–ion recombination are represented as the sum of all corresponding reaction collisions. Ionization and electron attachment occur anywhere in the discharge space. The electron attachment rate is lower than the ionization rate because of the smaller cross section. The electron detachment occurs in the sheath where the negative ion energy is high enough (see the threshold energies for the detachment processes in Tables III and IV). Similarly, the CF3+–CF4 reaction rate, which is again taken as the sum of all reactions, shows that the reactive collisions take place in the sheath. The positive–negative ion recombination is observed only in the bulk plasma and is the major loss process of negative ions.

The simulation results for the electric field, the particle densities and energies, and collision rates are in reasonable agreement with the simulation results of Denpoh and Nanbu16 except for the ion density profiles in the bulk plasma, which are parabolic in the present calculation. Concave ion density profiles are observed in other simulations of a CF4 discharge14,15 as well as in other electronegative discharges14 when ionization exceeds ion–ion recombination in the plasma–sheath interface. A possible explanation for the present results is that this simulation does not follow all CF4 positive ions because of their much lower density compared to the CF4+ density (see Sec. II). This simplification is done because the aim of the present model is actually to study the discharge properties in Ar/CF4 mixtures. Moreover, the concentration of CF2+ does not exceed 10% for etching purposes in practice, which suggests that the effect of all CF4 ions, except for CF4+, on the plasma parameters will be negligible in such mixtures (see the results below).
C. Ar/CF₄ mixtures

Figures 4, 5, and 6 show the structure of the discharge in an Ar/CF₄ mixture for a ratio of 0.9/0.1, 0.5/0.5, and 0.1/0.9, respectively. The electric field (a) and electron density (b) at four times in the rf cycle, the time-averaged ion densities (c), and the average electron (at four phases), Ar⁺ and F⁻ ion energies (d) are presented for each of the three gas compositions. The average energy of the CF₃⁻ ions is not presented since it has a similar profile and value as in a pure CF₄ discharge [see Fig. 2(c)]. The average energy of the CF₃⁻ ions is not given either, because its profile and value are similar to that of the F⁻ ions. Based on the results for pure Ar and CF₄ discharges, described above, a comparative analysis of the discharge structure in a mixture of Ar and CF₄ is carried out here.

At high concentration of Ar (90%) the structure of the discharge is similar to that of an electronegative discharge (Fig. 4). The electric field distribution resembles that of a pure Ar discharge [cf. Figs. 1(a) and 4(a)]. The major positive ions are Ar⁺ ions; the density of CF₃⁻ in the center of the bulk plasma is about 2 orders of magnitude lower than that of Ar⁺ [Fig. 4(c)]. Similar ion composition was measured in an Ar/CF₄ ICP, although quantitative comparison is difficult to make because of the differences in the operating conditions of capacitively and inductively coupled discharges.

Some features of electronegative discharges begin to appear in Fig. 4. The dominant negative carriers are not the electrons, but the negative ions (F⁻ to and a lesser extent CF₃⁻). In the bulk center the F⁻ ion density has a value of 1.4×10¹⁶ m⁻³, whereas the electron density is only 2.1×10¹⁵ m⁻³ [cf. Figs. 4(b) and 4(c)]. The rapid decrease in the electron density with the addition of even a small amount of CF₄ was also observed in an Ar/CF₄ ICP. The electron density profile is quite flat in the bulk plasma and it resembles that of a pure CF₄ discharge, but the peaks at the bulk–sheath interface are not yet formed. Experimental results also revealed a flat electron density profile in the bulk plasma at CF₄ concentrations up to 10%.

The average electron energy is around 3 eV in the bulk plasma [Fig. 4(d)] and its profile is similar to the one of a pure Ar discharge. The Ar⁺ ions have a maximum energy of about 3.5 eV at the electrodes. The F⁻ ions reach a maximum energy of 7 eV in the sheath. From the calculated recombination rates (not shown here) it is clear that the ion–CF₄ reactive collisions play no significant role in sustaining the discharge, because of the low concentration of CF₄ molecules.

At equal concentrations of Ar and CF₄ gas (Fig. 5) the discharge structure includes more electronegative features. The double layer structure in the electric field and the maxima in the electron density appear [Figs. 5(a) and 5(b)], as well as the electric field reversal at phases 0 and π. The electron density is about 5×10¹⁴ m⁻³ in the bulk, i.e., four times lower than for the 0.9/0.1 gas mixture. At the same time, the F⁻ ion density increases up to 2.4×10¹⁶ m⁻³ in the bulk. Similarly, the CF₃⁻ ion density is higher compared to the 0.9/0.1 gas mixture. The Ar⁺ ion is still the major positive ion [Fig. 5(c)] because of the larger ionization cross section of argon compared to that of CF₄. However, the density of the CF₃⁻ ions is only now less than a factor of 4 lower than the Ar⁺ ion density. Its value in the center is 7×10¹⁴ m⁻³ [compared to only 3×10¹⁴ m⁻³ at the 0.9/0.1 gas mixture in Fig. 4(c)], as is qualitatively expected because of the higher concentration of CF₄ molecules. The average electron energy is almost constant in the bulk plasma at around 5 eV [Fig. 5(d)]. The Ar⁺ ions have an average energy of 0.04 eV in the bulk plasma, and they reach a maximum average energy of 7 eV at the electrodes, which is two times higher than in the 0.9/0.1 Ar/CF₄ discharge. The average F⁻ ion energy is about 0.035 eV in the bulk plasma and it has a maximum value of 7 eV in the sheath.

At high concentration of CF₄ (90%) the discharge structure is definitely electronegative (Fig. 6). The double layer and the electron density maxima are well established [Figs. 6(a) and 6(b)]. A field reversal is observed at phases 0 and π. The major positive ion is now CF₃⁻ [Fig. 6(c)]. Indeed, the CF₃⁻ density in the bulk plasma has a value of 3×10¹⁶ m⁻³, whereas the Ar⁺ density is only 7×10¹⁵ m⁻³. Similar dependence of the number densities of the positive ions with the CF₄ content was measured in an inductively coupled Ar/CF₄ discharge. The F⁻ has a similar, but somewhat lower density than the CF₃⁻ and the CF₄ has a similar, but somewhat higher density than the Ar⁺. The electron density is 3×10¹⁴ m⁻³ in the bulk plasma and reaches a maxima of 6×10¹⁴ m⁻³ at the bulk–sheath interface. The average electron energy in the bulk is about 6 eV like in a pure CF₄ discharge [cf. Figs. 2(c) and 6(d)]. The maximum value of the average Ar⁺ ion energy is 32 eV. The increase of the Ar⁺ ion energy in the sheath with decreasing Ar concentration shows that the Ar⁺–Ar collisions are the main energy loss term for the Ar⁺ ions. The average F⁻ ion energy again reaches its maximum in the sheath with a value of around 8 eV.

The electron energy probability function (EEPF) \( f_n(e) = F_n(e) e^{-1/2} \) at the center of the discharge is shown in Fig. 7 for all simulated gas mixtures. The calculated EEPF in a pure Ar discharge confirms the previous simulated and measured results. The EEPF in a mixture of Ar and CF₄ changes its profile from Maxwellian like to Druyvesteyn like with the transition from electronegative to electronegative behavior of the discharge. The high-energy tail in the latter case is due to the strong electric field in the bulk (up to 1000 V/m) (see Fig. 3) in comparison with the weak electric field (up to 10V/m) in electronegative discharges. The explanation of the difference in the EEDF \( F_{n}(e) \) in discharges in electropositive and electronegative discharges can be found in Ref. 21. The calculated EEPF in a pure CF₄ discharge is in good agreement with that presented by Denpoh and Nanbu in Ref. 34 at the same operating conditions.

Finally, to compare the simulation results with the experimental data the developed model is carried out at operating conditions close to those presented in Ref. 11, i.e., for a distance between the electrodes of 6 cm, a pressure ranging from 30 to 100 mTorr and at CF₄ contents from 2% to 10%. The applied voltage amplitude is 240 V. The calculated and measured results for the electronegativity \( \alpha_0 = n_n/n_e \), where \( n_n \) and \( n_e \) denote the negative ion and electron densities.
The section data for electron–Ar and electron–

determined by the null collision method based on cross-

ing operating conditions: a distance between the electrodes

electron

2

1

This behavior is as expected since the attachment probability

IV. SUMMARY

ties, respectively) are presented in Fig. 8. Both measured and
calculated electronegativities increase with the CF4 content.
This behavior is as expected since the attachment probability
becomes higher with the CF4 content. However, the simul-
tations cannot yet predict the increase of the measured elec-
tronegativity with pressure. Indeed, the probabilities of all
t邀 kinds of electron–neutral collisions are proportional to the
neutral gas density and consequently to the pressure. As a
result the densities of all charged particles rise. Therefore the
probabilities of all production and loss processes in the
model increase with pressure but the ratios of negative ions
t邀 electrons stay more or less constant at least in the inves-
tigated pressure range.

A one-dimensional PIC/MC model has been developed
t邀 describe the structure of a cc rf discharge in a gas mixture
of Ar and CF4. The model follows five charged particles:
electrons, Ar++, CF3+, F-, and CF4. The collisions treated
by the Monte Carlo method include electron–Ar collisions,
electron–CF2 collisions, various kinds of collisions of CF3+, 1

F-, CF3-, or Ar++ with Ar or CF4, and positive–negative ion
recombination. The electron–neutral collision probability is
determined by the null collision method based on cross-
section data for electron–Ar and electron–CF4 collisions. The
Ar++–Ar collision probability is calculated in the same
way. Since not all collision cross-section data are available,
the present model uses several techniques to define the col-
ision probabilities even when the cross sections are un-
known. The probability for the positive–negative ion recom-
bination is determined from the recombination rate constant,
whereas the ion–neutral elastic and reactive collisions are
simulated by an ion–molecule collision model for endothermi-
c reactions.

The simulations are performed for 0.1/0.9, 0.5/0.5, and
0.9/0.1 ratios of Ar/CF4 mixture, and for pure Ar and pure
CF4 discharge. All calculations are carried out at the follow-

ing operating conditions: a distance between the electrodes
of 2.5 cm, V=200 V, and f=13.56 MHz. p=200 mTorr,
and γ=0. This model yields results for the electron and vari-
ous ion densities, their fluxes and energy distributions, the
collision rates, and the electric field and potential distribu-
tions.

First of all, the structures of the pure electropositive Ar

discharge and of the pure electronegative CF4 discharge are
clarified. Then the results for Ar/CF4 mixtures at different
ratios are presented and discussed, and the transition from an
electropositive to an electronegative discharge is illustrated.
It is observed that at high concentration of Ar (90%) the
structure of the discharge is similar to that of the elec-

tive discharge, although some features of electronegative
discharges, such as the abundance of negative ions, begin to
appear. The Ar++ density exceeds the CF3+ density by about 2
orders of magnitude. At equal concentration of Ar and CF4
the discharge shows more electronegative features. The
double layer structure and the electron density maxima in the
sheath, which are representative for an electronegative dis-
charge, appear. Electric field reversal is observed as well.
However, the major positive ion is still Ar++. At high CF4
centration the discharge behaves as a typical electronega-
tive discharge and CF3+ is the major positive ion. The results
show that the F- ions are the dominant negatively charged
species at all Ar/CF4 ratios investigated.

Finally, the calculated electronegativities in an Ar/CF4
discharge at a concentration of CF4 up to 10% over the pres-
sure range from 30 to 100 mTorr are compared with mea-
sured data and reasonable agreement is reached.

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